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MOSFET – Single, N-Channel, Small Signal, SOT-883 (XDFN3), 1.0 x 0.6 x 0.4 mm 30 V, 1000 mA



Features

- Single N-Channel MOSFET
- Ultra Low Profile SOT-883 (XDFN3) 1.0 x 0.6 x 0.4 mm for Extremely Thin Environments such as Portable Electronics
- Low R_{DS(on)} Solution in Ultra Small 1.0 x 0.6 mm Package
- 1.8 V Gate Drive
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- High Side Switch
- High Speed Interfacing
- Level Shift and Translate
- Optimized for DC–DC Converter Power Management in Ultra Portable Solutions

MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Pai	rameter		Symbol	Value	Units		
Drain-to-Source Vo	ltage		V _{DSS}	30	V		
Gate-to-Source Voltage			V _{GS}	±12	V		
Continuous Drain	Steady $T_A = 25^{\circ}C$		I _D	1000	mA		
Current (Note 1)	State	$T_{A} = 85^{\circ}C$ $T_{A} = 25^{\circ}C$		721			
	t ≤ 5 s	$T_A = 25^{\circ}C$		1050			
Power Dissipa- tion (Note 1)	Steady State	$T_A = 25^{\circ}C$	P _D	178	mW		
	t ≤ 5 s	T _A = 25°C		187			
Pulsed Drain Curre	nt	t _p = 10 μs	I _{DM}	2.6	А		
Operating Junction Temperature	and Storage	Э	T _J , T _{STG}	-55 to 150	°C		
Source Current (Body Diode) (Note 2)			۱ _S	187	mA		
Lead Temperature f (1/8" from case for		g Purposes	TL	260	°C		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Units
Junction-to-Ambient - Steady State (Note 1)	R _{θJA}	703	°C/W
Junction-to-Ambient – t \leq 5 s (Note 1)	$R_{\theta JA}$	670	

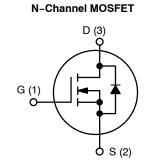
1. Surface Mounted on FR4 Board using the minimum recommended pad size, (or 2 mm²), 1 oz Cu.

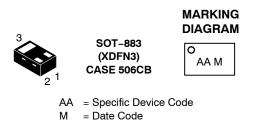


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MOSFET					
V _{(BR)DSS}	R _{DS(on)} MAX I _D MAX				
	0.155 Ω @ 4.5 V				
	0.168 Ω @ 3.7 V				
30 V	0.180 Ω @ 3.3 V	1000 mA			
	0.220 Ω @ 2.5 V				
	0.450 Ω @ 1.8 V				





ORDERING INFORMATION

Device	Package	Shipping [†]
NTNS4C69NTCG	SOT-883 (Pb-Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{2.} Pulse Test: pulse width \leq 300 $\mu s,$ duty cycle \leq 2%.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Test Co	ondition	Min	Тур	Max	Units
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V,	I _D = 250 μA	30			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J	I _D = 250 μA	, ref to 25°C		17		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V, V _{DS} = 24 V	$T_J = 25^{\circ}C$			1.0	μΑ
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V,	V _{GS} = 12 V			100	nA
ON CHARACTERISTICS (Note 3)							
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} = V _{DS}	, I _D = 10 μA	0.65		1.1	V
Negative Gate Threshold Temperature Coefficient	$V_{GS(TH)}/T_J$				-3.0		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 4.5 V,	, I _D = 300 mA		0.127	0.155	Ω
		V _{GS} = 3.7 V,	, I _D = 250 mA		0.135	0.168	
		V _{GS} = 3.3 V,	, I _D = 200 mA		0.140	0.180	

		V_{GS} = 2.5 V, I _D = 150 mA	0.170	0.220	
		V _{GS} = 1.8 V, I _D = 100 mA	0.300	0.450	
Forward Transconductance	9 FS	$V_{DS} = 5 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$	2.0		S
Source-Drain Diode Voltage	V _{SD}	V_{GS} = 0 V, I _S = 100 mA	0.7	1.0	V

CHARGES & CAPACITANCES

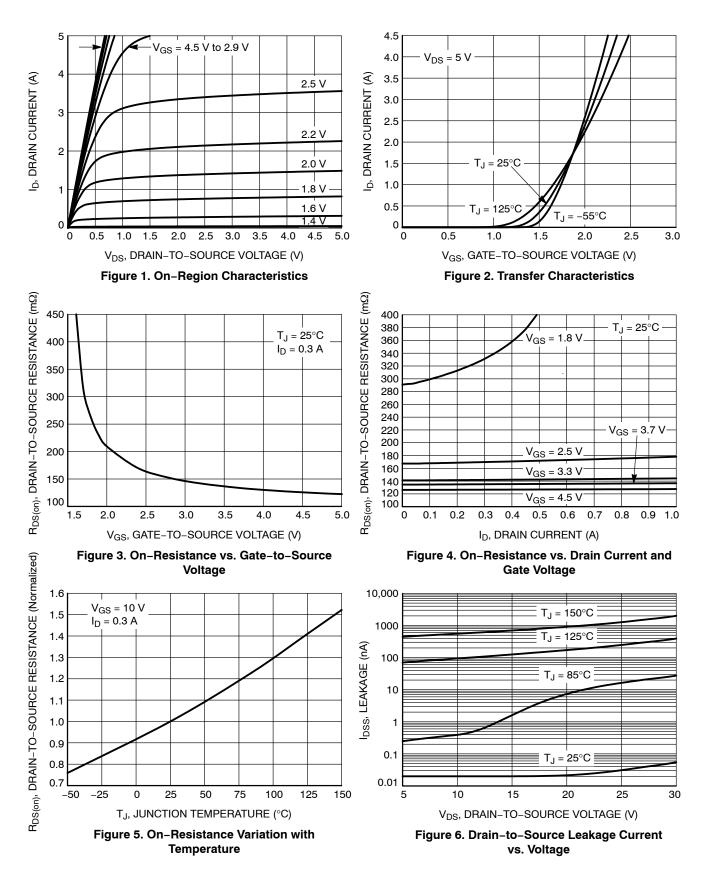
Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1 MHz, V _{DS} = 15 V	75	pF
Output Capacitance	C _{OSS}		34	
Reverse Transfer Capacitance	C _{RSS}		3.0	
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 4.5 V, V _{DS} = 15 V,	0.9	nC
Threshold Gate Charge	Q _{G(TH)}		0.1	
Gate-to-Source Charge	Q _{GS}	V_{GS} = 4.5 V, V_{DS} = 15 V, I _D = 200 mA	0.2	
Gate-to-Drain Charge	Q _{GD}]	0.1	

SWITCHING CHARACTERISTICS, VGS = 4.5 V (Note 3)

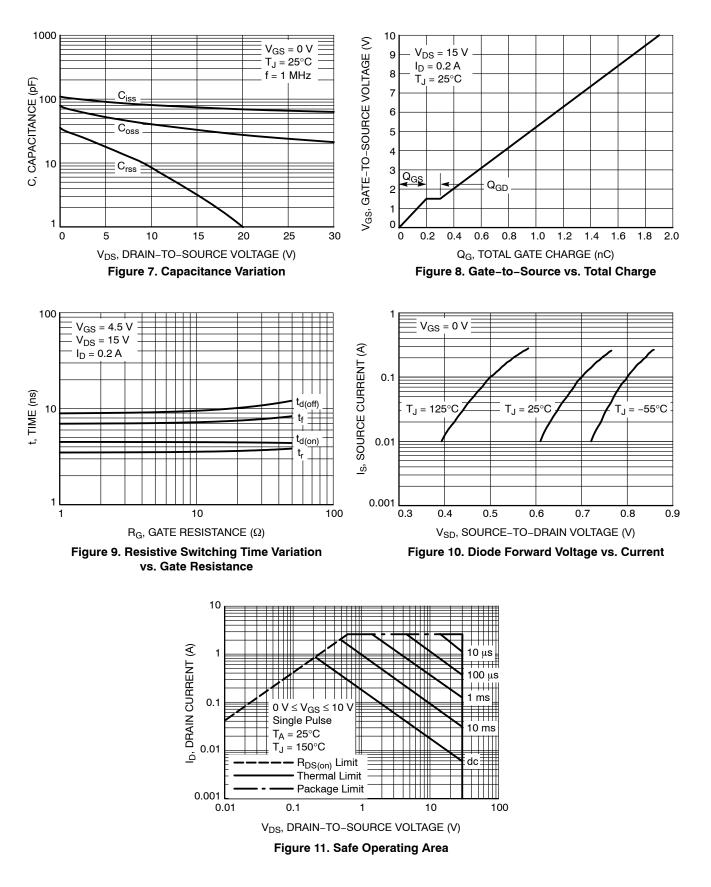
Turn-On Delay Time	t _{d(ON)}		4.5	ns
Rise Time	t _r	V _{GS} = 4.5 V, V _{DD} = 15 V,	3.5	
Turn-Off Delay Time	t _{d(OFF)}	$I_D = 200 \text{ mA}, R_G = 2 \Omega$	9.0	
Fall Time	t _f		7.0	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



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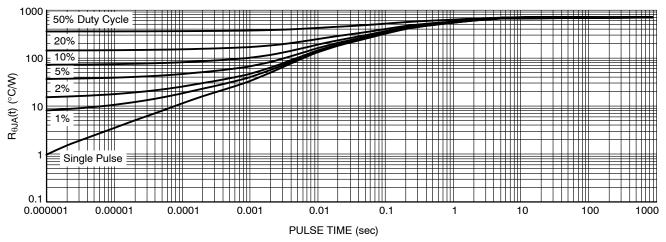
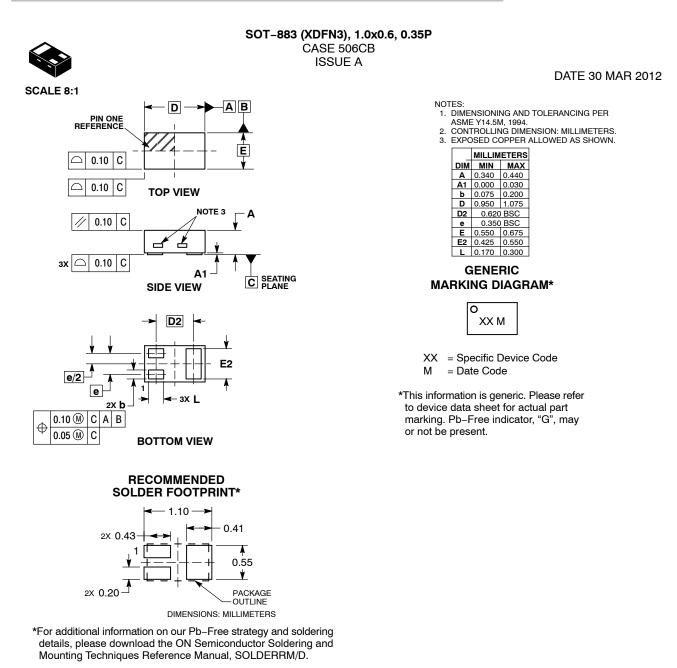


Figure 12. Thermal Characteristics





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